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|                                     | BECT - 303   |            |
|-------------------------------------|--|------------|
|                                     | Roll No  |            |
|                                     | •  |            |
| Odd Semester Examination, 2019-2020 |  |            |
|                                     | B. TECH. (ECE/CSE ,SEMESTER- III)  |            |
|                                     | DIGITAL ELECTRONICS  |            |
|                                     | Max  | Marks:100  |
|                                     | Time: 03:00 Hours  Total no. of p  |            |
|                                     |  |            |
|                                     | Note: Attempt all questions.   | 4 5 30     |
|                                     | Q1. Attempt any four questions from the following:   | 4x5=20     |
|                                     | a) Convert following:  |            |
|                                     | i. $(35614)_7 = ()_{12}$<br>ii. $(100100111000.0111)_{BCD} = ()_{10}$  |            |
|                                     | ii. $(100100111000.0111)_{BCD} = ()_{10}$<br>b) $f(A,B,C,D,E) = \sum m(0,1,7,9,11,13,15,16,17,23,25,27)$   |            |
|                                     | at 1 1 C Harring agnetion using one AND and one OK gate only.  |            |
|                                     | V = (A + R) (A + C)  |            |
|                                     | d) Perform (1011) <sub>2</sub> -(0100) <sub>2</sub> using 1 s complement method.   |            |
|                                     | Write short note on De Morgan's theorem.   |            |
|                                     | f) Encode the data bits 0101 into a seven bit even parity Hamming Code.  |            |
|                                     | Q2. Attempt any four questions from the following:   | 4x5=20     |
|                                     | a) Design a full adder using two half adder.   |            |
|                                     | b) Implement a full adder using 8:1 multiplexer.   |            |
|                                     | Design four hit Priority Encoder.  |            |
|                                     | d) Implement the following function using 4 to 16 line decoder.  |            |
|                                     | $f = \sum m(1,2,4,7,8,11,12,13)$<br>e) Write short notes on PAL and PLA.   |            |
|                                     | · · · · · · · · · · · · · · · · · · ·  |            |
|                                     |  | 2x10=20    |
|                                     | Q3. Attempt any two questions from the following:  | 2X10-20    |
|                                     | C D flin flon Evoluin its applications and disadvantages.  |            |
|                                     | <ul><li>a) Design a S-R flip flop. Explain its appreciations</li><li>b) Explain the operation of 4 bit Ring counter. Also draw its timing diagram.</li><li>c) What is race around condition? How it can be removed, explain.</li></ul> |            |
|                                     | c) What is race around condition? How it can be removed, expenses  |            |
|                                     | Q4. Attempt any two questions from the following:  | 2x10=20    |
|                                     |  |            |
|                                     | b) Design a Two input NOR gate using CMOS. Also explain its parameters   |            |
|                                     | c) Explain the working of TTL logic family.  |            |
|                                     | Q5. Attempt any two questions from the following:  | 2x10=20    |
|                                     | Line Incident work? Discuss different types of Ha  | zards.     |
|                                     | a) What is meant by Hazard in a logic network. Disease explain its working b) Draw circuit diagram of MOS dynamic RAM cell. Also explain its working b) Draw circuit diagram of MOS dynamic RAM cell. Also explain its working b)      | 5.         |
|                                     | <ul> <li>b) Draw circuit diagram of MOS dynamic RAW cent. Also explain a</li> <li>c) A 16x4 size memory is available. Expand its word size so as to obtain a 16</li> </ul>   | x8 memory. |
|                                     | v)   |            |